

### Vishay Semiconductors

# **Small Signal Fast Switching Diodes**



#### **FEATURES**

- Silicon epitaxial planar diodes
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

# Ph

RoHS

**HALOGEN** 

FREE

#### **APPLICATIONS**

· Extreme fast switches

# **DESIGN SUPPORT TOOLS** click logo to get started



#### **MECHANICAL DATA**

Case: DO-35 (DO-204AH)
Weight: approx. 125 mg
Cathode band color: black
Packaging codes / options:

TR/10K per 13" reel (52 mm tape), 50K/box TAP/10K per ammopack (52 mm tape), 50K/box

PARTS TABLE					
PART	ORDERING CODE	TYPE MARKING	CIRCUIT CONFIGURATION	REMARKS	
1N4448	1N4448TAP or 1N4448TR	V4448	Single	Tape and reel / ammopack	

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Repetitive peak reverse voltage		V <sub>RRM</sub>	100	V	
Reverse voltage		V <sub>R</sub>	75	V	
Peak forward surge current	t <sub>p</sub> = 1 μs	I <sub>FSM</sub>	2	Α	
Repetitive peak forward current		I <sub>FRM</sub>	500	mA	
Forward continuous current		I <sub>F</sub>	300	mA	
Average forward current	$V_R = 0$	I <sub>F(AV)</sub>	150	mA	
Dower dissipation	I = 4 mm, T <sub>L</sub> = 45 °C	P <sub>tot</sub>	440	mW	
Power dissipation	I = 4 mm, T <sub>L</sub> ≤ 25 °C	P <sub>tot</sub>	500	mW	

THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air	I = 4 mm, T <sub>L</sub> = constant	R <sub>thJA</sub>	350	K/W	
Junction temperature		Tj	175	°C	
Storage temperature range		T <sub>stg</sub>	-65 to +150	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Forward voltage	I <sub>F</sub> = 5 mA	V <sub>F</sub>	0.620		0.720	V	
Forward voltage	I <sub>F</sub> = 100 mA	V <sub>F</sub>			1	V	
	V <sub>R</sub> = 20 V	I <sub>R</sub>			25	nA	
Reverse current	V <sub>R</sub> = 20 V, T <sub>j</sub> = 150 °C	I <sub>R</sub>			50	μA	
	V <sub>R</sub> = 75 V	I <sub>R</sub>			5	μA	
Breakdown voltage	$I_R = 100 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	V <sub>(BR)</sub>	100			V	
Diode capacitance	$V_R = 0$ , $f = 1$ MHz, $V_{HF} = 50$ mV	C <sub>D</sub>			4	pF	
Rectification efficiency	V <sub>HF</sub> = 2 V, f = 100 MHz	ηr	45			%	
	$I_F = I_R = 10 \text{ mA}, i_R = 1 \text{ mA}$	t <sub>rr</sub>			8	ns	
Reverse recovery time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $I_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$	t <sub>rr</sub>			4	ns	

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

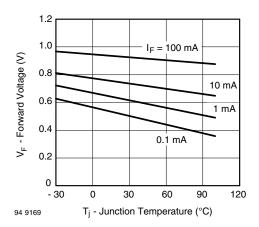


Fig. 1 - Forward Voltage vs. Junction Temperature

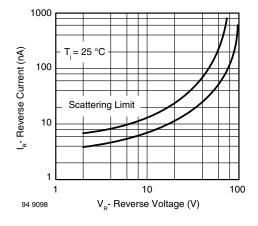


Fig. 3 - Reverse Current vs. Reverse Voltage

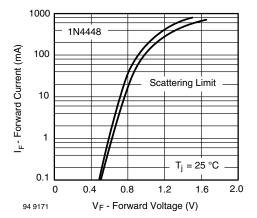
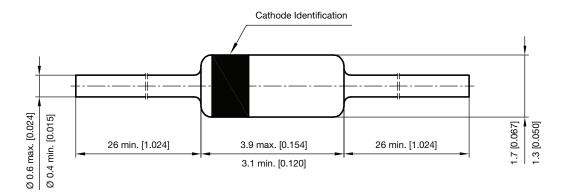


Fig. 2 - Forward Current vs. Forward Voltage

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### PACKAGE DIMENSIONS in millimeters (inches): DO-35 (DO-204AH)



Rev. 6 - Date: 19. December 2011 Document no.: SB-V-3906.04-031(4)

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